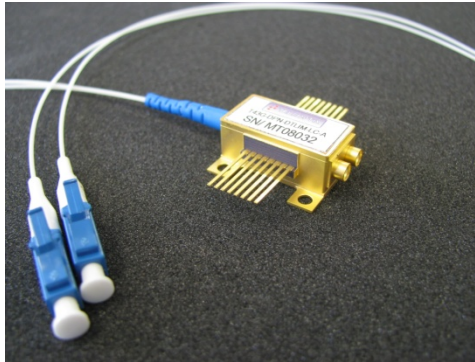


PRELIMINARY DATASHEET



Description: The balanced photo-receiver module integrates a dual UTC photodiode array with a differential trans-impedance linear amplifier suitable for 40 Gbit/s and >100 Gbit/s optical transmissions using electronic post-processing. Thanks to the optical characteristics of the UTC photodiodes associated with a high performances linear amplifier giving an overall O/E -3dBm adjustable bandwidth up to 32.5 GHz, this dual-photodiode receiver is well adapted to address 100 Gbit/s PM-QPSK with coherent detection and/or 8/16 QAM modulation formats for even higher optical transmission bit-rates. The module is in a 16 pin package format with GPPO and LC/PC optical connectors.

Main Features:

- Up to +7 dBm optical input power per photodiode
- Butterfly package with GPPO™ connectors
- Low polarisation dependent loss (typ. : 0.2 dB)
- Differential RF output, AC-coupled
- Operating case temperature: 0°...70°C

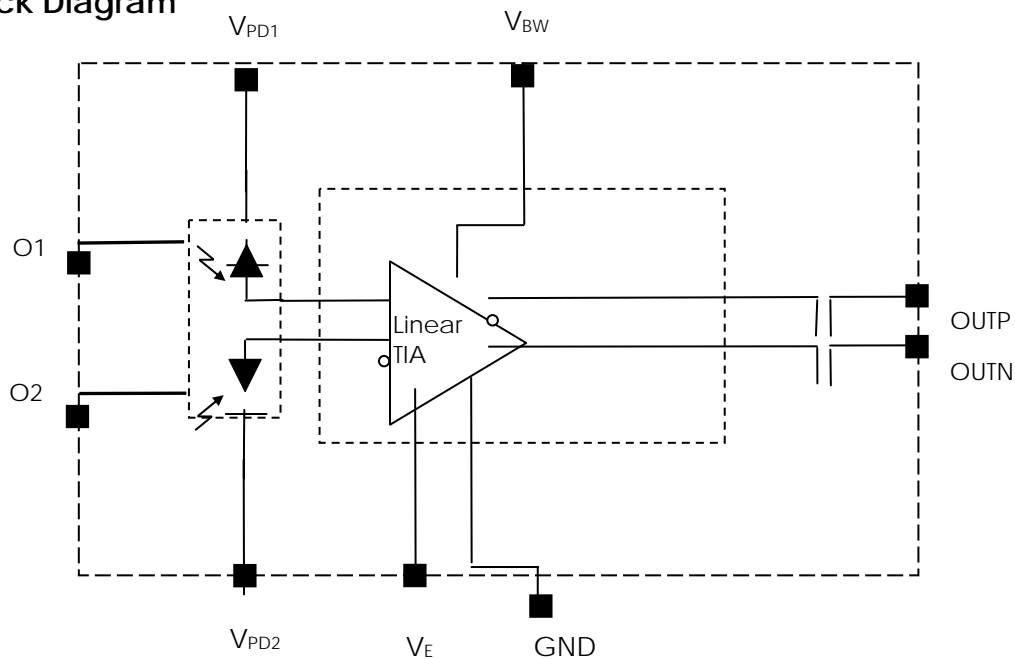
Applications :

- 40 Gbit/s optical transmissions
- 100 Gbit/s PM-QPSK with coherent detection, 8/16 QAM, optical transmissions WDM optical

Enclosed data :

1. Block Diagram
2. Absolute Maximum Ratings
3. Typical Operating Conditions
4. Main characteristics
5. Connector and Fibre Specification
6. Mechanical Dimensions
7. Pin Allocation
8. Ordering Information

1. Block Diagram



$V_{PD1,2}$: Photodiodes power supply voltages
 V_E : Amplifier power supply voltage
 V_{BW} : Bandwidth adjustment control voltage

2. Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Unit
PD bias voltage	$V_{PD1,2}$	- 0.5	+ 3.5	V
Amplifier power supply voltage	V_E	TBD	TBD	V
Bandwidth adjustment voltage	V_{BW}	TBD	TBD	V
Optical input power	$P_{OptIN\ mean}$	-	+ 7	dBm
Operating temperature	T_{OP}	0	+ 70	°C
Storage temperature	T_{ST}	- 40	+ 80	°C

3. Typical Operating Conditions

Parameter	Symbol	Typ.	Unit
Amplifier power supply voltage	V_E	- 4.5	V
Amplifier power supply current	I_E	- 200	mA
Bandwidth adjustment voltage	V_{BW}	- 3.5	V
Bandwidth adjustment current	I_{BW}	- 6	mA
Amplifier power dissipation	P_{DC}	< 920	mW
PD bias voltage	V_{PD1}, V_{PD2}	+2.0	V

4. Main Characteristics

N°	Parameter	Symbol	Conditions	Min	Typ.	Max	Unit
1	Wavelength range	λ		1525		1620	nm
2	Optical Input Power	$P_{\text{OptIN}}_{\text{mean}}$			+3		dBm
3	PD _{1,2} responsivity	$R_{\text{PD1,2}}$	$V_{\text{PD1,2}} = + 2.0 \text{ V}$		0.6	-	A/W
4	PD dark current	I_{Dark}	$V_{\text{PD1,2}} = + 2.0 \text{ V}$	-	10	100	nA
5	PDL _{1,2} polarisation dependent loss	$\text{PDL}_{1,2}$	$V_{\text{PD1}} = + 2.0 \text{ V}$	-	0.2	0.5	dB
6	3 dB bandwidth ⁽¹⁾	$f_{-3\text{dB}}$	$V_{\text{PD1,2}} = +2.3\text{V}$ $V_E = -4.5 \text{ V}$ $V_E = -3.5 \text{ V}$		32.5	-	GHz
7	Electrical return loss	S_{22}	DC ~ 20 GHz 20 GHz ~ 45 GHz	-	-10 - 7	-	dB
8	Small signal differential conversion gain ^(2,5)	$G_{\text{Conv_diff}}$	$V_E = -4.5 \text{ V}$ $V_E = -3.5 \text{ V}$	-	150	-	V/W
10	Optical path delay ⁽⁴⁾	O_{PD}	-	-	0.5	1	ps
13	Power dissipation	P_{DC}	$V_E = -4.5 \text{ V}$ $V_E = -3.5 \text{ V}$	-	915		mW

Notes : (1) : Measurements performed in single-ended operation with 0 dBm optical input power.

(2) : $G_{\text{Conv_diff}} = \text{Eye_amp}(\text{differential}) / P_{\text{opt_INpp}}(\text{differential})$.

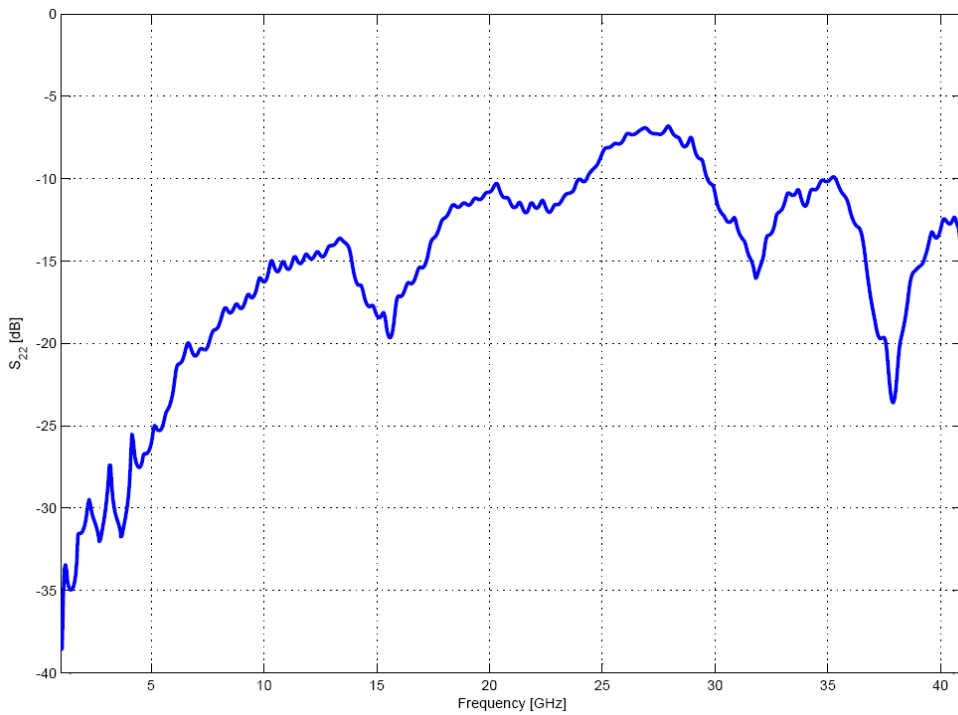
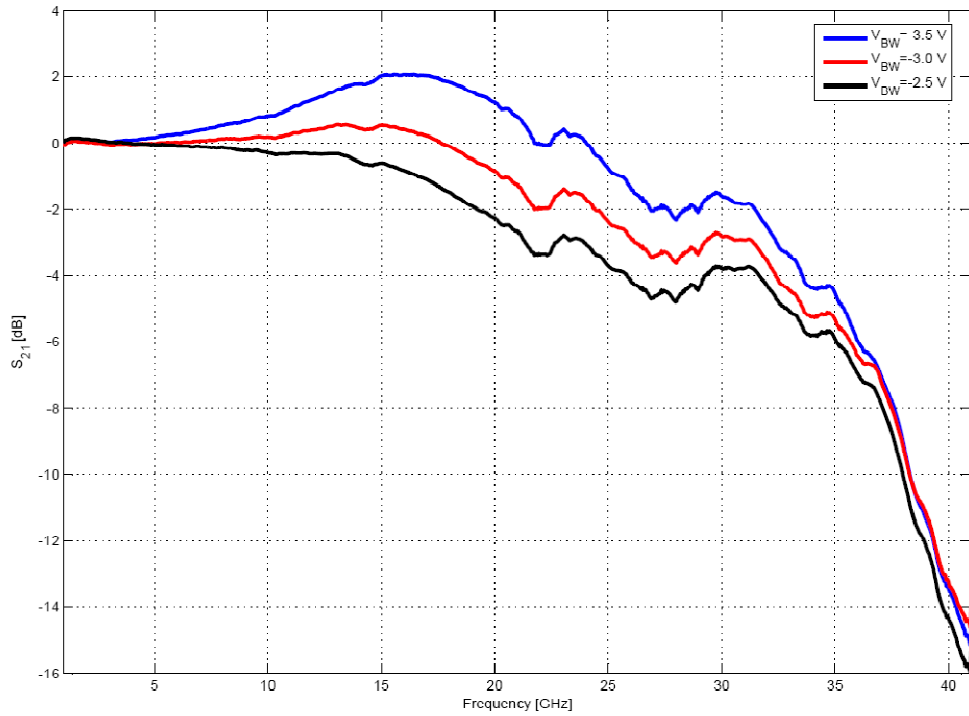
$P_{\text{optIN_mean}}$ (injected on both photodiodes) = -10dBm.

Evaluated from NRZ eye diagram measurements at 43 Gbit/s.

(4) : Between the two input fibres.

(5) : Differential output voltage.

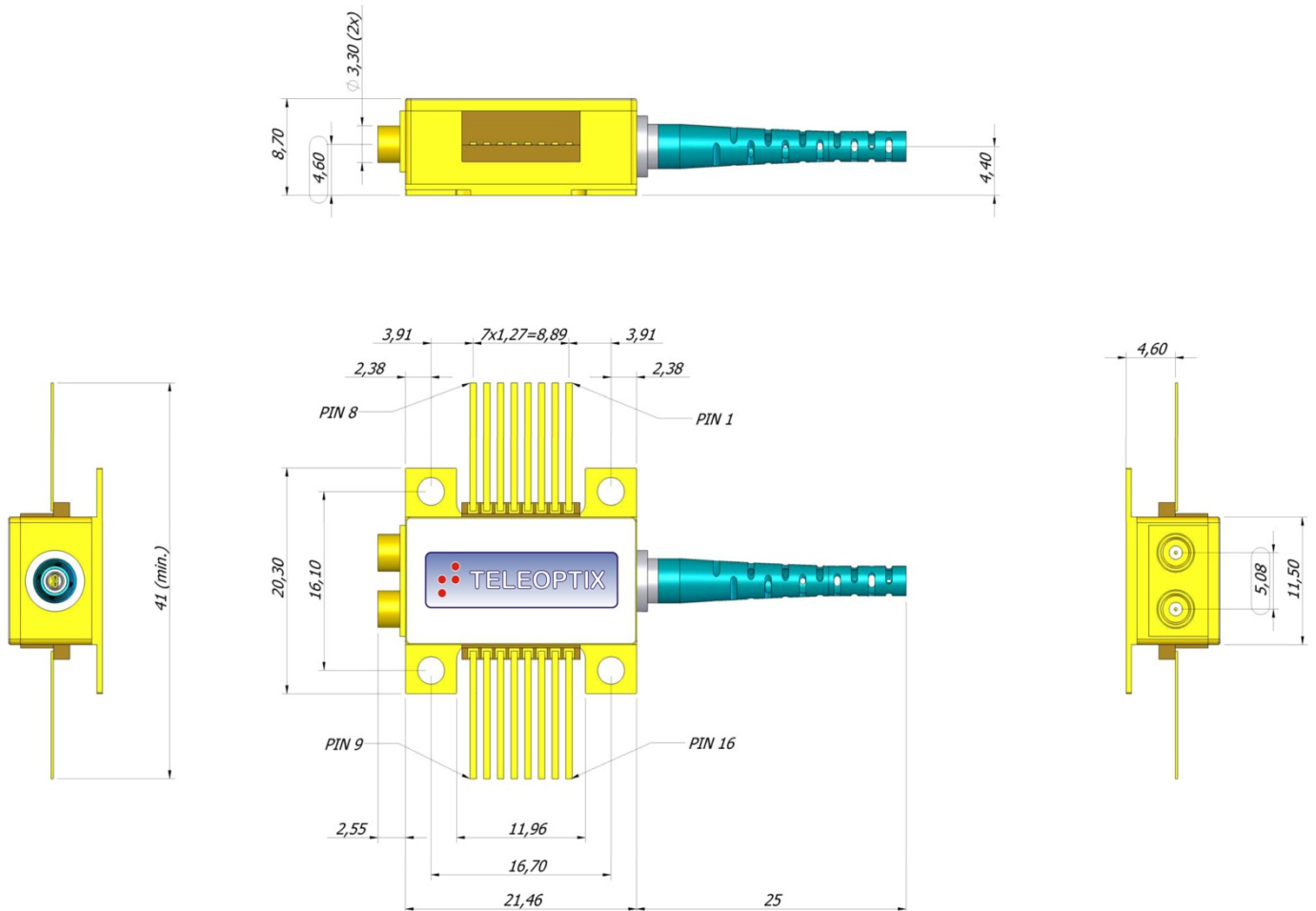
O/E S_{21} and E/E S_{22} measured using an Agilent Lightwave Component Analyzer in single-ended operation:



5. Connector and Fibre Specification

Parameter	Specification	Unit
Type	SMF	-
Jacket diameter	900	μm
Length	700 +/- 20	mm
Fibre Bend Radius	25 min	mm
Connector	LC/PC	-

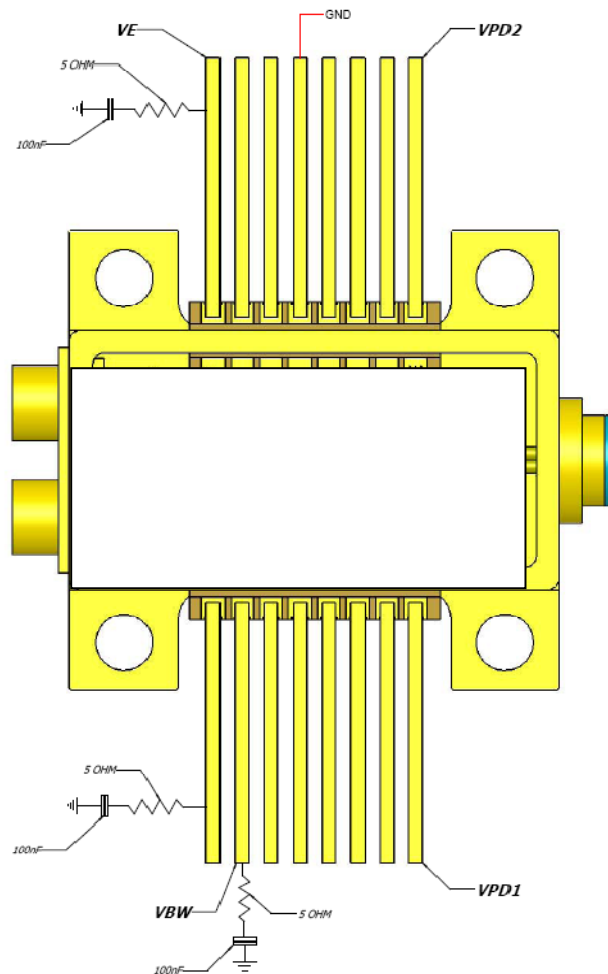
6. Mechanical Dimensions



7. Pin Allocation (subject to change)

Pin	Name	Pin	Name
1	V _{PD2}	16	V _{PD1}
2	No internal connection	15	No internal connection
3	No internal connection	14	No internal connection
4	No internal connection	13	No internal connection
5	GND	12	No internal connection
6	No internal connection	11	No internal connection
7	No internal connection	10	V _{BW}
8	V _E	9	-

5 ohm resistors and 100nF capacitors must be added externally as reported here below:





Balanced PHOTORECEIVER
with Linear TIA
Module name: DualPIN-DTLin Rx

8. Ordering Information:

For orders or more information, please contact our sales office:

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